Analog Devices Welcomes
Hittite Microwave Corporation

NO CONTENT ON THE ATTACHED DOCUMENT HAS CHANGED
HMC1020LP4E
RMS POWER DETECTOR
SINGLE-ENDED, DC - 3.9 GHz

Typical Applications
The HMC1020LP4E is ideal for:
• Log --> Root-Mean-Square (RMS) Conversion
• Tx/Rx Signal Strength Indication (TSSI/RSSI)
• RF Power Amplifier Efficiency Control
• Receiver Automatic Gain Control
• Transmitter Power Control

Features
Broadband Single-Ended RF Input
±1 dB Detection Accuracy to 3.9 GHz
Input Dynamic Range: -65 dBm to +7 dBm
RF Signal Wave Shape & Crest Factor Independent
Digitally Programmable Integration Bandwidth
Excellent Temperature Stability
Power-Down Mode
24 Lead 4x4mm SMT Package: 16mm²

Functional Diagram

General Descriptions
The HMC1020LP4E Power Detector is designed for
RF power measurement and control applications for
frequencies up to 3.9 GHz. The detector provides
an accurate RMS representation of any broadband,
single-ended RF/IF input signal. The output is a tem-
perature compensated, monotonic representation of
real signal power, measured with an input sensing
range of 72 dB.
The HMC1020LP4E is ideally suited to those wide
bandwidth, wide dynamic range applications requir-
ing repeatable measurement of real signal power,
especially where RF/IF wave shape and/or crest factor
change with time.
The integration bandwidth of the HMC1020LP4E is
digitally programmable with the use of input pins
SCI-4 over a range of more than 3 decades. This
allows the user to dynamically set the operation
bandwidth and also permits the detection of different
 types of modulations on the same platform.

HMC1020LP4E features an internal op-amp at the out-
put stage, which provides for slope / intercept adjust-
ments and enables controller application.

Electrical Specifications I

<table>
<thead>
<tr>
<th></th>
<th></th>
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<th></th>
<th></th>
<th></th>
</tr>
</thead>
<tbody>
<tr>
<td>Dynamic Range (±1dB Error)</td>
<td>100</td>
<td>900</td>
<td>1900</td>
<td>2200</td>
<td>2700</td>
</tr>
<tr>
<td>Input Frequency</td>
<td>72</td>
<td>72</td>
<td>71</td>
<td>70</td>
<td>66</td>
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<td>Single Ended Input Configuration</td>
<td>58</td>
<td>53</td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>Deviation vs Temperature: (Over full temperature range -40 °C to 85 °C). Deviation is measured from reference, which is the same WCDMA input at 25 °C.</td>
<td>1 dB</td>
<td></td>
<td></td>
<td></td>
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</tr>
</tbody>
</table>

[1] With WCDMA 4 Carrier (TMII-64 DPCH)
**RMS POWER DETECTOR**  
**SINGLE-ENDED, DC - 3.9 GHz**

**Electrical Specifications II**  
$T_A = +25 \, ^\circ\text{C}$, $Vcc = 5\, \text{V}$, $\text{Sci4} = \text{Sci1} = 0\, \text{V}$, $\text{Sci3} = \text{Sci2} = 5\, \text{V}$, Unless Otherwise Noted

<table>
<thead>
<tr>
<th></th>
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<th></th>
<th></th>
<th></th>
<th></th>
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</tr>
</thead>
<tbody>
<tr>
<td>Input Frequency</td>
<td>100</td>
<td>900</td>
<td>1900</td>
<td>2200</td>
<td>2700</td>
<td>3500</td>
<td>3900</td>
</tr>
</tbody>
</table>

**Modulation Deviation** (Output deviation from reference, which is measured with CW input at equivalent input signal power)

<table>
<thead>
<tr>
<th>Modulation</th>
<th>Deviation</th>
</tr>
</thead>
<tbody>
<tr>
<td>WCDMA 4 Carrier (TM1-64 DPCH) at +25 °C</td>
<td>0.1 dB</td>
</tr>
<tr>
<td>WCDMA 4 Carrier (TM1-64 DPCH) at +85 °C</td>
<td>0.1 dB</td>
</tr>
<tr>
<td>WCDMA 4 Carrier (TM1-64 DPCH) at -40 °C</td>
<td>0.1 dB</td>
</tr>
</tbody>
</table>

**Logarithmic Slope and Intercept** [1]

<table>
<thead>
<tr>
<th></th>
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</thead>
<tbody>
<tr>
<td>Logarithmic Slope</td>
<td>35.0</td>
<td>35.2</td>
<td>36.0</td>
<td>36.6</td>
<td>37.9</td>
<td>41.5</td>
<td>44.4</td>
</tr>
<tr>
<td>Logarithmic Intercept</td>
<td>-68.2</td>
<td>-67.9</td>
<td>-66.5</td>
<td>-65.6</td>
<td>-63.6</td>
<td>-58.7</td>
<td>-55.3</td>
</tr>
<tr>
<td>Max. Input Power at ±1dB Error</td>
<td>7</td>
<td>7</td>
<td>7</td>
<td>7</td>
<td>5</td>
<td>2</td>
<td>0</td>
</tr>
<tr>
<td>Min. Input Power at ±1dB Error</td>
<td>-65</td>
<td>-65</td>
<td>-64</td>
<td>-63</td>
<td>-61</td>
<td>-56</td>
<td>-53</td>
</tr>
</tbody>
</table>

[1] With WCDMA 4 Carrier (TM1-64 DPCH)

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**RMSOUT vs. Pin with Different Modulations @ 1900 MHz** [1]

![RMSOUT vs. Pin with Different Modulations @ 1900 MHz](image)

**RMSOUT Error vs. Pin with Different Modulations @ 1900 MHz** [1]

![RMSOUT Error vs. Pin with Different Modulations @ 1900 MHz](image)

[1] Data was taken at Sci4=Sci1=0V, Sci3=Sci2=5V, shortest integration time is for SCI=0000, allowed longest integration time is for SCI=1100

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Fax: 978-250-3373  
Order On-line at www.hittite.com  
Application Support: Phone: 978-250-3343 or apps@hittite.com
**Electrical Specifications III**

$T_A = +25 \, ^\circ \text{C}$, $Vcc = 5V$, $Sci4 = Sci1 = 0V$, $Sci3 = Sci2 = 5V$, Unless Otherwise Noted

<table>
<thead>
<tr>
<th>Parameter</th>
<th>Conditions</th>
<th>Min</th>
<th>Typ.</th>
<th>Max</th>
<th>Units</th>
</tr>
</thead>
<tbody>
<tr>
<td><strong>Single-Ended Input Configuration</strong></td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>Input Network Return Loss</td>
<td>up to 3.9 GHz</td>
<td>&gt; 15</td>
<td></td>
<td></td>
<td>dB</td>
</tr>
<tr>
<td>Input Resistance between INP and INN</td>
<td>Between pins 3 and 4</td>
<td>100</td>
<td></td>
<td></td>
<td>Ω</td>
</tr>
<tr>
<td>Input Voltage Range</td>
<td>AC coupled peak voltage at INP</td>
<td></td>
<td></td>
<td>0.85</td>
<td>V</td>
</tr>
<tr>
<td><strong>RMSOUT Output</strong></td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>Output Voltage Range</td>
<td></td>
<td></td>
<td></td>
<td>0.13</td>
<td>to</td>
</tr>
<tr>
<td>Source/Sink Current Compliance</td>
<td>RMSOUT held at VCC/2</td>
<td></td>
<td></td>
<td>8</td>
<td>/</td>
</tr>
<tr>
<td>Output Slew Rate (rise / fall)</td>
<td>$Sci4=Sci3=Sci2=Sci1=0V$, $Cofs=1nF$</td>
<td>24</td>
<td>/</td>
<td>1.9</td>
<td>$10^6$</td>
</tr>
<tr>
<td><strong>VSET Input (Negative Feedback Terminal)</strong></td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>Input Voltage Range</td>
<td>For control applications with nominal slope/intercept settings</td>
<td></td>
<td></td>
<td>0.13</td>
<td>to</td>
</tr>
<tr>
<td>Input Resistance</td>
<td></td>
<td></td>
<td></td>
<td></td>
<td>5</td>
</tr>
<tr>
<td><strong>SCI1-4 Inputs, ENX Logic Input (Power Down Control)</strong></td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>Input High Voltage</td>
<td></td>
<td></td>
<td></td>
<td>0.7xVCC</td>
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</tr>
<tr>
<td>Input Low Voltage</td>
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<td></td>
<td>0.3xVCC</td>
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<td>Input High Current</td>
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<td></td>
<td>1</td>
</tr>
<tr>
<td>Input Low Current</td>
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<td></td>
<td>1</td>
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<tr>
<td>Input Capacitance</td>
<td></td>
<td></td>
<td></td>
<td></td>
<td>0.5</td>
</tr>
<tr>
<td><strong>Power Supply</strong></td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>Supply Voltage</td>
<td></td>
<td></td>
<td></td>
<td>4.5</td>
<td>5</td>
</tr>
<tr>
<td>Supply Current with no input power</td>
<td></td>
<td></td>
<td></td>
<td></td>
<td>55</td>
</tr>
<tr>
<td>Supply Current with Pin = -20dBm</td>
<td></td>
<td></td>
<td></td>
<td>58</td>
<td></td>
</tr>
<tr>
<td>Standby Mode Supply Current</td>
<td></td>
<td></td>
<td></td>
<td></td>
<td>5</td>
</tr>
</tbody>
</table>
HMC1020LP4E
RMS POWER DETECTOR
SINGLE-ENDED, DC - 3.9 GHz

**RMSOUT & Error vs. Pin @ 100 MHz**

- **RMSOUT (V)** vs. **ERROR (dB)** vs. **INPUT POWER (dBm)**
- **Data** taken at Sci4=Sci1=0V, Sci3=Sci2=5V, shortest integration time is for SCI=0000, allowed longest integration time is for SCI=1100
- **WCDMA 4 carriers** input waveform

**RMSOUT & Error vs. Pin @ 900 MHz**

- **RMSOUT (V)** vs. **ERROR (dB)** vs. **INPUT POWER (dBm)**

**RMSOUT & Error vs. Pin @ 1900 MHz**

- **RMSOUT (V)** vs. **ERROR (dB)** vs. **INPUT POWER (dBm)**

**RMSOUT & Error vs. Pin @ 2200 MHz**

- **RMSOUT (V)** vs. **ERROR (dB)** vs. **INPUT POWER (dBm)**

**RMSOUT & Error vs. Pin @ 2700 MHz**

- **RMSOUT (V)** vs. **ERROR (dB)** vs. **INPUT POWER (dBm)**

**RMSOUT & Error vs. Pin @ 3500 MHz**

- **RMSOUT (V)** vs. **ERROR (dB)** vs. **INPUT POWER (dBm)**
HMC1020LP4E
RMS POWER DETECTOR
SINGLE-ENDED, DC - 3.9 GHz

RMSOUT & Error vs. Pin @ 3900 MHz

Intercept vs. Frequency

Slope vs. Frequency

RMSOUT vs. Pin with WCDMA 4 Carrier @ +25 °C

RMSOUT Error vs. Pin with WCDMA 4 Carrier @ +25 °C wrt +25 °C Response

RMSOUT Error vs. Pin with WCDMA 4 Carrier @ +85 °C wrt +25 °C Response

[1] Data was taken at Sci4=Sci1=0V, Sci3=Sci2=5V, shortest integration time is for SCI=-0000, allowed longest integration time is for SCI=1100
[2] WCDMA 4 carriers input waveform
HMC1020LP4E
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RMSOUT Error vs. Pin with WCDMA 4 Carrier @ -40 °C wrt +25 °C Response [1]

RMSOUT Error vs. Pin with CW @ +25 °C [1]

RMSOUT vs. Pin with CW & WCDMA 4 Carrier @ 1900 MHz & +25 °C [1]

Reading Error for WCDMA 4 Carrier wrt CW Response @ +25 °C [1]

RMSOUT vs. Pin w/ CW & WCDMA 4 Carrier @ 1900 MHz & +85 °C [1]

[1] Data was taken at Sci4=Sci1=0V, Sci3=Sci2=5V, shortest integration time is for SCI=0000, allowed longest integration time is for SCI=1100
RMS POWER DETECTOR
SINGLE-ENDED, DC - 3.9 GHz

Reading Error for WCDMA 4 Carrier wrt CW Response @ +85 °C [1]

RMSOUT vs. Pin w/ CW & WCDMA 4 Carrier @ 1900 MHz & -40 °C [1]

Reading Error for WCDMA 4 Carrier wrt CW Response @ -40 °C [1]

Output Response with SCI = 0000 @ 1900 MHz

Output Response with SCI = 1100 @ 1900 MHz

Typical Supply Current vs. Pin, Vcc = 5V

[1] Data was taken at Sci4=Sci1=0V, Sci3=Sci2=5V, shortest integration time is for SCI=0000, allowed longest integration time is for SCI=1100
Input Return Loss vs. Frequency

Output Ripple & Rise/Fall Time vs. Integration Setting
## Absolute Maximum Ratings

<table>
<thead>
<tr>
<th>Parameter</th>
<th>Specification</th>
</tr>
</thead>
<tbody>
<tr>
<td>Power Supply Voltage (Vcc)</td>
<td>5.6V</td>
</tr>
<tr>
<td>Single Ended RF Input Power</td>
<td>10 dBm</td>
</tr>
<tr>
<td>Single Ended Input Voltage</td>
<td>Vcc ± 0.6V</td>
</tr>
<tr>
<td>Junction Temperature</td>
<td>125 °C</td>
</tr>
<tr>
<td>Continuous Pdiss (T = 85°C) (Derate 32.45 mW/°C above 85°C)</td>
<td>1.39 W</td>
</tr>
<tr>
<td>Thermal Resistance (Rth) (junction to ground paddle)</td>
<td>28.68 °C/W</td>
</tr>
<tr>
<td>Storage Temperature</td>
<td>-65 to +150 °C</td>
</tr>
<tr>
<td>Operating Temperature</td>
<td>-40 to +85 °C</td>
</tr>
<tr>
<td>ESD Sensitivity (HBM)</td>
<td>Class 1B</td>
</tr>
</tbody>
</table>

### Outline Drawing

**Notes:**
1. Leadframe Material: Copper Alloy
2. Dimensions are in Inches [Millimeters]
3. Lead Spacing Tolerance is Non-Cumulative
4. Pad Burr Length Shall Be 0.15mm Maximum.
5. Package Warp Shall Not Exceed 0.05mm.
6. All Ground Leads and Ground Paddle Must Be Soldered to PCB RF Ground.
7. Refer to HMC Application Note For Suggested PCB Land Pattern.

### Package Information

<table>
<thead>
<tr>
<th>Part Number</th>
<th>Package Body Material</th>
<th>Lead Finish</th>
<th>MSL Rating</th>
<th>Package Marking [1]</th>
</tr>
</thead>
<tbody>
<tr>
<td>HMC1020LP4E</td>
<td>RoHS-compliant Low Stress Injection Molded Plastic</td>
<td>100% matte Sn</td>
<td>MSL1 [2]</td>
<td>H1020 XXXX</td>
</tr>
</tbody>
</table>

[1] 4-Digit lot number XXXX
## Pin Descriptions

<table>
<thead>
<tr>
<th>Pin Number</th>
<th>Function</th>
<th>Description</th>
<th>Interface Schematic</th>
</tr>
</thead>
<tbody>
<tr>
<td>1, 16, 21, 23</td>
<td>Vcc</td>
<td>Bias Supply. Connect supply voltage to these pins with appropriate filtering.</td>
<td><img src="image" alt="Interface Schematic for Vcc" /></td>
</tr>
<tr>
<td>2, 5, 6, 8, 11 - 13, 22, 24</td>
<td>GND</td>
<td>Package bottom has an exposed metal paddle that must be connected to RF/DC ground.</td>
<td><img src="image" alt="Interface Schematic for GND" /></td>
</tr>
<tr>
<td>3, 4</td>
<td>INP, INN</td>
<td>RF input pins.</td>
<td><img src="image" alt="Interface Schematic for INP, INN" /></td>
</tr>
<tr>
<td>7</td>
<td>ENX</td>
<td>Disable pin. Connect to GND for normal operation. Applying voltage V&gt;0.8xVcc will initiate power saving mode.</td>
<td><img src="image" alt="Interface Schematic for ENX" /></td>
</tr>
</tbody>
</table>
### Pin Descriptions (Continued)

<table>
<thead>
<tr>
<th>Pin Number</th>
<th>Function</th>
<th>Description</th>
<th>Interface Schematic</th>
</tr>
</thead>
<tbody>
<tr>
<td>9, 10</td>
<td>COFSA, COFSB</td>
<td>Input high pass filter capacitor. Connect a capacitor between COFSA and COFSB to determine 3 dB point of input signal high-pass filter.</td>
<td><img src="image1" alt="Interface Schematic" /></td>
</tr>
<tr>
<td>14</td>
<td>VSET</td>
<td>Set input point for controller mode.</td>
<td><img src="image2" alt="Interface Schematic" /></td>
</tr>
<tr>
<td>15</td>
<td>RMSOUT</td>
<td>Logarithmic output that provides an indication of mean square input power.</td>
<td><img src="image3" alt="Interface Schematic" /></td>
</tr>
<tr>
<td>17, 18, 19, 20</td>
<td>SCI1, SCI2, SCI3, SCI4</td>
<td>Digital input pins that control the internal integration time constant for mean square calculation. SCI4 is the most significant bit. Set V=0.2xVcc to disable. Shortest integration time is for SCI=0000, allowed longest integration time is for SCI=1100 (1101, 1110 and 1111 SCI settings are forbidden states). Each step changes the integration time by 1 octave.</td>
<td><img src="image4" alt="Interface Schematic" /></td>
</tr>
</tbody>
</table>
**Evaluation PCB**

The circuit board used in the application should use RF circuit design techniques. Signal lines should have 50 ohm impedance while the package ground leads and exposed paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation circuit board shown is available from Hittite upon request.

Board is configured with wideband single-ended input interface suitable for input signal frequencies above 100 MHz. Refer to wideband single-ended input interface section in application information for operating with signals below 100 MHz.

### List of Materials for Evaluation PCB

<table>
<thead>
<tr>
<th>Item</th>
<th>Description</th>
</tr>
</thead>
<tbody>
<tr>
<td>J1, J2</td>
<td>SMA Connector</td>
</tr>
<tr>
<td>TP1 - TP9</td>
<td>DC Pin</td>
</tr>
<tr>
<td>C1, C10, C16</td>
<td>100 pF Capacitor, 0402 Pkg.</td>
</tr>
<tr>
<td>C2, C5, C11, C17</td>
<td>100 nF Capacitor, 0402 Pkg.</td>
</tr>
<tr>
<td>C3, C4, C6</td>
<td>1000 pF Capacitor, 0402 Pkg.</td>
</tr>
<tr>
<td>R2, R12 - R15</td>
<td>10K Ohm Resistor, 0402 Pkg.</td>
</tr>
<tr>
<td>R3 - R5, R9, R10</td>
<td>0 Ohm Resistor, 0402 Pkg.</td>
</tr>
<tr>
<td>R6, R7</td>
<td>4.7K Ohm Resistor, 0402 Pkg.</td>
</tr>
<tr>
<td>U1</td>
<td>HMC1020LP4E RMS Power Detector</td>
</tr>
<tr>
<td>PCB [1]</td>
<td>128683-1 Evaluation PCB</td>
</tr>
</tbody>
</table>

[1] Circuit Board Material: Rogers 4350 or Arlon 25FR

### Evaluation Order Information

<table>
<thead>
<tr>
<th>Item</th>
<th>Content</th>
<th>Part Number</th>
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</thead>
<tbody>
<tr>
<td>Evaluation PCB</td>
<td>HMC1020LP4E Evaluation PCB</td>
<td>EVAL01-HMC1020LP4E</td>
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</table>
HMC1020LP4E
RMS POWER DETECTOR
SINGLE-ENDED, DC - 3.9 GHz

Application Circuit

PLACE THESE AS CLOSE TO THE PACKAGE AS POSSIBLE
**Application Information**

**Principle of Operation**

The HMC1020LP4E power detector is the optimal solution for monitoring and controlling transmitted and received signal power, measuring the incident RF signal power, and then generating an output signal representing the input power level.

The HMC1020LP4E is a monolithic true-RMS detector, which in fact is an analog calculator, designed to measure the actual RMS power of the input signal, independent of the modulated signal waveform complexity or modulation scheme. At the core of an RMS detector is a full-wave rectifier, log/antilog circuit, and an integrator. The RMS output signal is directly proportional to the logarithm of the time-average of $V_{in}^2$. The bias block also contains temperature compensation circuits which stabilize output accuracy over the entire operating temperature range. The DC offset cancellation circuit actively cancels internal offsets so that even very small input signal levels can be measured accurately.

The HMC1020LP4E achieves exceptional RF power measurement accuracy independent of the modulation of the carrier, with the system architecture shown in the block diagram figure. The relation between the HMC1020LP4E’s RMSOUT output and the RF input power is given below:

$$\text{RMSOUT} = \frac{1}{k} \ln \left( \beta k G^2 \int V_{in}^2 \, dt \right)$$

$$P_{IN} = \text{RMSOUT} / \text{[log-slope]} + \text{[log-intercept]}, \text{dBm}$$

**Configuration For The Typical Application**

The HMC1020LP4E is a logarithmic RMS detector that can be directly driven with a single-ended 50-Ohm RF source. The integrated broadband single-ended input interface of HMC1020LP4E eliminates the requirement for an external balun transformer or a matching network. The HMC1020LP4E can be operated from DC to 3.9 GHz by using only standard DC blocking capacitors. This simple input interface provides cost and PCB area reductions and increases measurement repeatability.

The RMS output signal is typically connected to VSET through a resistive network providing a Pin -> RMSOUT transfer characteristic slope of 35.2 mV/dB (at 900 MHz). However the RMS output can be re-scaled to “magnify” a specific portion of the input sensing range, and to fully utilize the dynamic range of the RMS output. Refer to the section under the “log-slope and intercept” heading for details.
Due to part-to-part variations in log-slope and log-intercept, a system-level calibration is recommended to satisfy absolute accuracy requirements; refer to the “System Calibration” section for more details.

**Broadband Single-Ended Input Interface**

The HMC1020LP4E operates with a single-ended input interface and requires only two external DC blocking capacitors and an external 50 Ohm resistor. The HMC1020LP4E input interface shown below provides a compact, broadband solution.

Note that the provided single-ended input interface covers the whole operating spectrum of the HMC1020LP4E and does not require matching/tuning for different frequencies. The performance of the HMC1020LP4E at different frequencies is shown below:
RMS Output Interface and Transient Response

The HMC1020LP4E features digital input pins (SCI1-SCI4) that control the internal integration time constant. Output transient response is determined by the digital integration controls, and output load conditions.

Shortest integration time is for SCI=0000, allowed longest integration time is for SCI=1100 (1101, 1110 and 1111 SCI settings are forbidden states).

Using larger values of SCI will narrow the operating bandwidth of the integrator, resulting in a longer averaging time interval and a more filtered output signal. It will also slow the power detector’s transient response. A larger SCI value favors output accuracy over speed. For the fastest possible transient settling times set SCI to 0000. This configuration will operate the integrator at its widest possible bandwidth, resulting in short averaging time-interval and an output signal with little filtering. For most applications an SCI setting may be selected to maintain a balance between speed and accuracy. Furthermore, error performance over modulation bandwidth is dependent on the SCI setting. For example, modulations with relatively low frequency components and high crest factors may require higher SCI (integration) settings.

Table 1: Transient Response vs. SCI Setting [1]:

<table>
<thead>
<tr>
<th>SCI4,3,2,1</th>
<th>RMSOUT Rise-Time 10% -&gt; 90% (µs) [3]</th>
<th>RMSOUT Rise Setting Time (µs) [2]</th>
<th>RMSOUT Fall-time 100% -&gt; 10% (µs) [4]</th>
</tr>
</thead>
<tbody>
<tr>
<td>Pin = 0 dbm</td>
<td>Pin = -20 dbm</td>
<td>Pin = -40 dbm</td>
<td>Pin = 0 dbm</td>
</tr>
<tr>
<td>0000</td>
<td>0.0686</td>
<td>0.044</td>
<td>0.053</td>
</tr>
<tr>
<td>0010</td>
<td>0.0684</td>
<td>0.05</td>
<td>0.093</td>
</tr>
<tr>
<td>0100</td>
<td>0.076</td>
<td>0.066</td>
<td>0.875</td>
</tr>
<tr>
<td>0110</td>
<td>1.624</td>
<td>3.432</td>
<td>4.84</td>
</tr>
<tr>
<td>1000</td>
<td>8.6</td>
<td>15.32</td>
<td>23.4</td>
</tr>
<tr>
<td>1010</td>
<td>38.6</td>
<td>65.8</td>
<td>109.6</td>
</tr>
<tr>
<td>1100</td>
<td>186</td>
<td>325</td>
<td>509</td>
</tr>
</tbody>
</table>

[1] Input signal is 1900 MHz CW -tone switched on and off
[2] Measured from RF switching edge to 1dB (input referred) settling of RMSOUT.
[3] Measured from 10% to 90%
[4] Measured from 100% to 90%
RMS POWER DETECTOR
SINGLE-ENDED, DC - 3.9 GHz

**Rise Time\(^{[1]}\) vs. SCI Setting over Input Power**

For increased load drive capability, consider a buffer amplifier on the RMS output. Using an integrating amplifier on the RMS output allows for an alternative treatment for faster settling times. An external amplifier optimized for transient settling can also provide additional RMS filtering, when operating HMC1020LP4E with a lower SCI value.

Following figures show how the peak-to-peak ripple decreases with higher SCI settings along with the RF pulse response over different modulations.

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\(^{[1]}\) Measured from 10% to 90%

\(^{[2]}\) Measured from RF switching edge to 1dB (input referred) settling of RMSOUT.

\(^{[3]}\) Measured from 100% to 100%
HMC1020LP4E
RMS POWER DETECTOR
SINGLE-ENDED, DC - 3.9 GHz

Residual Ripple for 900 Mhz
WiBRO @ SCI=0100

Residual Ripple for 900 Mhz
LTE Downlink @ SCI=0100

Residual Ripple for 900 Mhz
WCDMA4 @ SCI=0011

Residual Ripple for 900 Mhz
LTE Downlink @ SCI=0100

Residual Ripple for 900 Mhz
WCDMA4 @ SCI=0000
**LOG-Slope and Intercept**

The HMC1020LP4E provides for an adjustment of output scale with the use of an integrated operational amplifier. Logarithmic slope and intercept can be adjusted to “magnify” a specific portion of the input sensing range, and to fully utilize the dynamic range of the RMS output.

A log-slope of 35.2 mV/dB (@1900 MHz) is set by connecting RMS Output to VSET through a resistor network for β=1 (see application schematic).

The log-slope is adjusted by applying the appropriate resistors on the RMS and VSET pins. Log-intercept is adjusted by applying a DC voltage to the VSET pin.

\[
\beta = \frac{1}{2} \left( \frac{R_{FBK}}{R_{SET}} \right)
\]

\[
\text{Optimized intercept} = \text{log_intercept} - \left( \frac{R_{FBK}}{R_{SET}} \right) \times V_{BL INE}
\]

When \( R_{FBK} = 0 \) to set RMSOUT=VSET then \( \beta = 1/2 \)

If \( R_{SET} \) is not populated, then \( \beta = \frac{1}{2} \times \left( \frac{R_{FBK}}{R_{FBK} \parallel R_{SHUNT}} \right) \) and intercept is at nominal value.

Example: The logarithmic slope can be simply increased by choosing appropriate \( R_{FBK} \) and \( R_{SHUNT} \) values while not populating the RSET resistor on the evaluation board to keep the intercept at nominal value.

Setting \( R_{FBK} = 4.7\,\text{KΩ} \) and \( R_{SHUNT} = 2.2\,\text{KΩ} \) results in an optimized slope of:

Optimized Slope = \( \beta \times \text{log_slope} = 1.57 \times 36.9\,\text{mV} / \text{dB} \)

Optimized Slope = 58 mV / dB

**Slope Adjustment**

![Graph showing slope adjustment](image-url)
**DC Offset Compensation Loop**

Internal DC offsets, which are input signal dependent, require continuous cancellation. Offset cancellation is a critical function needed for maintenance of measurement accuracy and sensitivity. The DC offset cancellation loop performs this function, and its response is largely defined by the capacitance (COFS) connected between COFSA, COFS pins.

COFS capacitor sets the loop bandwidth of the DC offset compensations. Higher COFS values are required for measuring lower RF frequencies. The optimal loop bandwidth setting will allow internal offsets to be cancelled at a minimally acceptable speed.

\[
\text{DC Offset Cancellation Loop} = \frac{1}{\pi(5000)(C_{\text{COFS}} + 20 \times 10^{-12})} \quad \text{Bandwidth}, \text{ Hz}
\]

For example: loop bandwidth for DC cancellation with COFS = 1nF, bandwidth is ~62 kHz
Standby Mode

The ENX pin can be used to force the power detector into a low-power standby mode. As ENX is deactivated, power is restored to all of the circuits. There is no memory of previous conditions. Coming out of standby mode, internal integration and COFS capacitors will require recharging, so if large SCI values have been chosen, the wake-up time will be lengthened.

Modulation Performance – Crest factor performance

The HMC1020LP4E is capable of detecting the average power of RF signals with complex modulation schemes with exceptional accuracy. The proprietary RMS detection core is optimized to accurately detect the RMS power of the modulated RF signals with very high crest factors. This crest factor immune detection architecture of HMC1020LP4E results in detection accuracy of better than 0.2 dB over the entire operating frequency and temperature range. The response of the HMC1020LP4E to a WCDMA4TM test signal is compared with the CW response in the following plots:

Reading Error for WCDMA 4 Carrier wrt CW Response @ +25 °C

![Reading Error for WCDMA 4 Carrier wrt CW Response @ +25 °C](image)

Reading Error for WCDMA 4 Carrier wrt CW Response @ 2200MHz

![Reading Error for WCDMA 4 Carrier wrt CW Response @ 2200MHz](image)

RMSOUT Error vs. Crest Factor over Frequency

![RMSOUT Error vs. Crest Factor over Frequency](image)
System Calibration

Due to part-to-part variations in log-slope and log-intercept, a system-level calibration is recommended to satisfy absolute accuracy requirements. When performing this calibration, two test points near the top end and bottom-end of the desired detection dynamic range should be chosen. It is best to measure the calibration points in the regions (of frequency and amplitude) where accuracy is most important. The log-slope and log-intercept parameters should be derived and then stored in nonvolatile memory. These parameters relate the RMSOUT output voltage reading of HMC1020LP4E to the actual RMS power level as shown below:

\[ P_{\text{IN}} = \text{RMSOUT} / [\text{log-slope}] + [\text{log-intercept}], \text{dBm} \]

The derivation procedure of the log-slope and log-intercept parameters is elaborated below:

For example if the following two calibration points were measured at 2.2 GHz:

- With RMSOUT = 2.0338V at Pin = -10 dBm,
- and RMSOUT = 0.5967V at Pin = -50 dBm

slope calibration constant = SCC

\[ \text{SCC} = (-50+10)/(0.5967-2.0338) = 27.83 \text{ dB/V} \]

intercept calibration constant = ICC

\[ \text{ICC} = \text{Pin} - \text{SCC} \times \text{RMSOUT} = -10 - 27.83 \times 2.0338 = -66.60 \text{ dBm} \]

Now performing a power measurement at -30 dBm:

RMSOUT measures 1.3089V

\[ [\text{Measured Pin}] = [\text{Measured RMSOUT}] \times \text{SCC} + \text{ICC} \]

[Measured Pin] = 1.3089*27.83 – 66.60 = -30.17 dBm

An error of only 0.17 dB

Factory system calibration measurements should be made using an input signal representative of the application. If the power detector is intended to operate over a wide range of frequencies, then a central frequency should be chosen for calibration.

Layout Considerations

- Mount RF input coupling capacitors close to the INP and INP pins.
- Solder the heat slug on the package underside to a grounded island which can draw heat away from the die with low thermal impedance. The grounded island should be at RF ground potential.
- Connect power detector ground to the RF ground plane, and mount the supply decoupling capacitors close to the supply pins.

Definitions

- Log-slope: slope of \( P_{\text{IN}} \rightarrow \text{RMSOUT} \) transfer characteristic. In units of mV/dB
- Log-intercept: x-axis intercept of \( P_{\text{IN}} \rightarrow \text{RMSOUT} \) transfer characteristic. In units of dBm.
- RMS Output Error: The difference between the measured \( P_{\text{IN}} \) and actual \( P_{\text{IN}} \) using a line of best fit.\n  \[ [\text{measured}_P_{\text{IN}}] = [\text{measured}_\text{RMSOUT}] / [\text{best-fit-slope}] + [\text{best-fit-intercept}], \text{dBm} \]
- Input Dynamic Range: the range of average input power for which there is a corresponding RMS output voltage with “RMS Output Error” falling within a specific error tolerance.
- Crest Factor: Peak power to average power ratio for time-varying signals.